

# **DC DIP Phototransistor Optocoupler**

### Features

- High isolation 5300 VRMS
- DC input with transistor output
- Operating temperature range 55 °C to 125 °C
- RoHS compliance
- REACH compliance
- Halogen free
- Regulatory Approvals
  - UL UL1577 (Pending Approval)
  - VDE EN60747-5-5 (Pending Approval)
  - CQC GB4943.1, GB8898 (Pending Approval)
  - IEC60065, IEC60950 (Pending Approval)

## Description

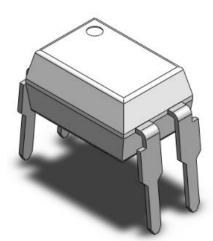
The CT521-1GB consists of a photo transistor optically coupled to a gallium arsenide Infraredemitting diode in a DIP package.

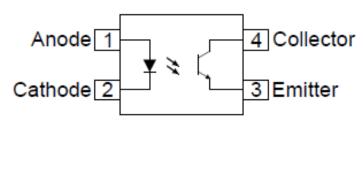
## **Applications**

- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

## **Package Outline**











# Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
Viso	Isolation voltage	5300	Vrms	
Ртот	Total power dissipation	200	mW	
Topr	Operating temperature	-55 ~ +125	°C	
Тѕтс	Storage temperature	-55 ~ +150	°C	
Tsol	Soldering temperature	260	°C	
Emitter				
IF	Forward current	60	mA	
IF(TRANS)	Peak transient current (≤1µs P.W,300pps)	1000	mA	
VR	Reverse voltage	6	V	
PD	Emitter power dissipation	100	mW	
Detector				
Pc	Detector power dissipation	150	mW	
B <sub>VCEO</sub>	Collector-Emitter Breakdown Voltage	80	V	
BVECO	Emitter-Collector Breakdown Voltage	7	V	
lc	Collector Current	80	mA	



## **Electrical Characteristics** $T_A = 25^{\circ}C$ (unless otherwise specified)

#### **Emitter Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward voltage	IF=10mA	-	1.25	1.4	V	
I <sub>R</sub>	Reverse Current	$V_R = 6V$	-	-	5	μΑ	
CIN	Input Capacitance	f= 1MHz	-	30	-	pF	

#### **Detector Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
BVCEO	Collector-Emitter Breakdown	I <sub>C</sub> = 100μA	55	-	-	V	
B <sub>VECO</sub>	Emitter-Collector Breakdown	I <sub>E</sub> = 100μA	7	-	-	V	
		V <sub>CE</sub> = 24V, I <sub>F</sub> =0mA	-	-	100	nA	
ICEO	Collector-Emitter Dark Current	V <sub>CE</sub> = 24V, I <sub>F</sub> =0mA,Ta = 85°C	-	-	50	μA	

#### **Transfer Characteristics**

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
CTR	Current Transfer Ratio	IF= 5mA, V <sub>CE</sub> = 5V	100	-	600	%	
CIK		I <sub>F</sub> = 1mA, V <sub>CE</sub> = 0.4V	30	-	-	%	
Variant	Collector-Emitter Saturation	IF= 1mA, Ic= 0.2mA			0.4	V	
Vce(sat)	Voltage	IF= IIIIA, IC= 0.2IIIA	-	-	0.4		
Rio	Isolation Resistance	VIO= 500VDC	5x10 <sup>10</sup>	-	-	Ω	
C <sub>IO</sub>	Isolation Capacitance	f= 1MHz	-	0.25	1	pF	

# Switching Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
tr	Rise Time		-		16		
t <sub>f</sub>	Fall Time	Ic= 2mA, VcE= 2V	-		16	μS	
t <sub>on</sub>	Turn-on time	R <sub>L</sub> = 100Ω	-		20		
t <sub>off</sub>	Turn-off time		-		20	μS	



1.8

2.0

20V

100 110

80

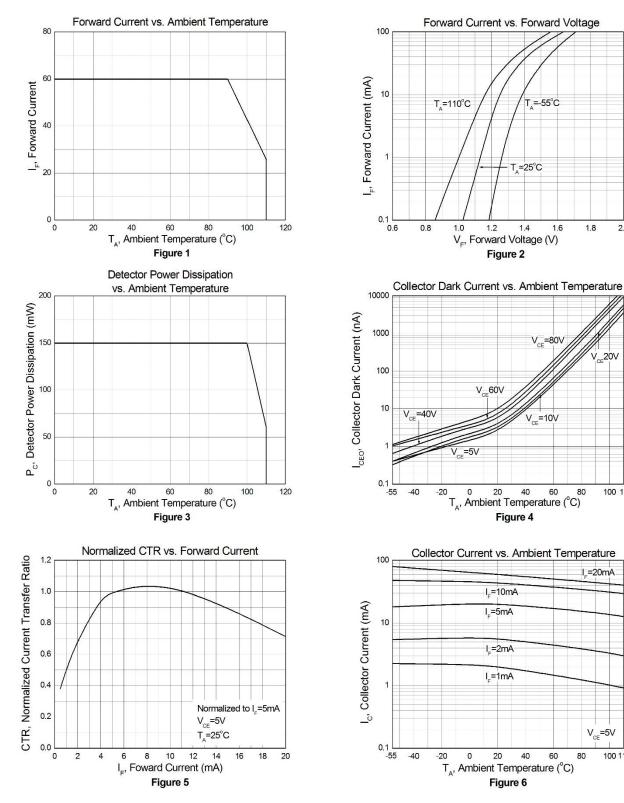
I\_=20mA

V<sub>CF</sub>=5V

100 110

80

# **Typical Characteristic Curves**





# **CT521-1GB**

P\_(MAX.)

50

10

# **DC DIP Phototransistor Optocoupler**

I\_=1mA

vs. Collector Current

=2m

I\_=5mA

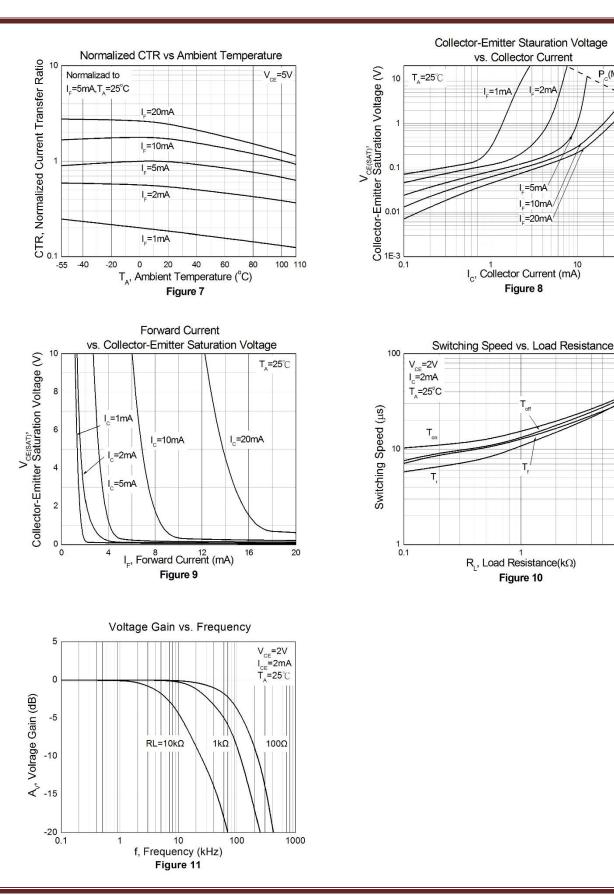
I\_=10mA I\_=20mA

I<sub>c</sub>, Collector Current (mA)

Figure 8

 $R_L$ , Load Resistance(k $\Omega$ )

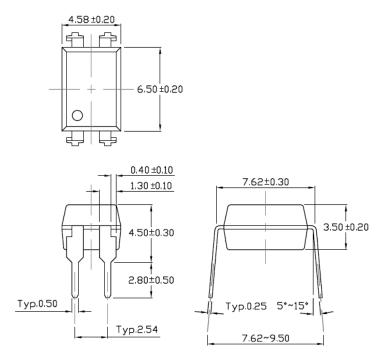
Figure 10



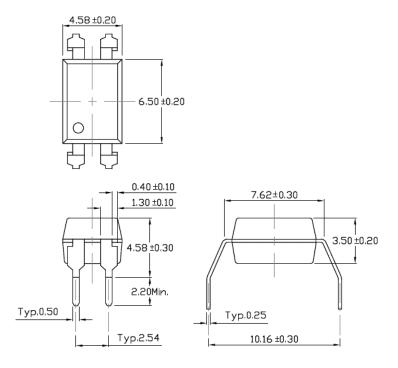


### Package Dimension Dimensions in mm unless otherwise stated

### Standard DIP – Through Hole

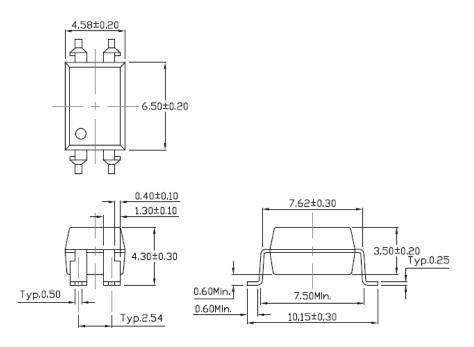


#### Gullwing (400mil) Lead Forming – Through Hole (M Type)

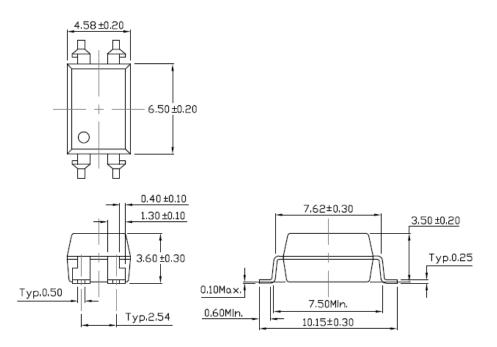




### Surface Mount Lead Forming (S Type)

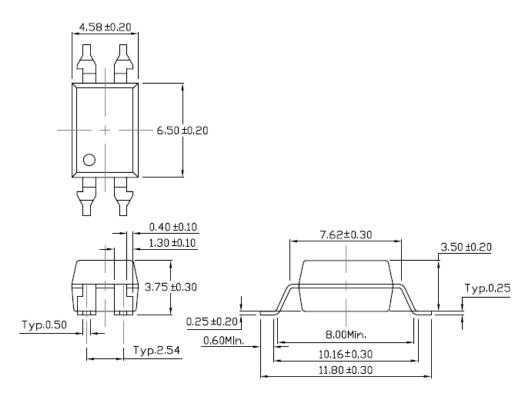


## Surface Mount (Low Profile) Lead Forming (SL Type)





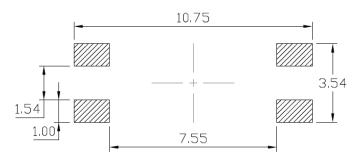
### Surface Mount (Gullwing) Lead Forming (SLM Type)



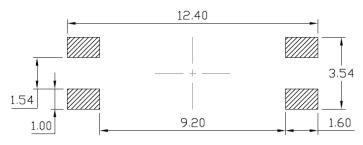


## Recommended Solder Mask Dimensions in mm unless otherwise stated

#### Surface Mount Lead Forming & Surface Mount (Low Profile) Lead Forming



#### Surface Mount (Gullwing) Lead Forming



# **Marking Information**



#### Note:

- CT : Denotes "CT Micro"
- 521-1 : Part Number
- GB : CTR Rank
- V : VDE Safety Option (V or none)
- Y : Fiscal Year
- WW : Work Week
- K : Manufacturing Code



# **Ordering Information**

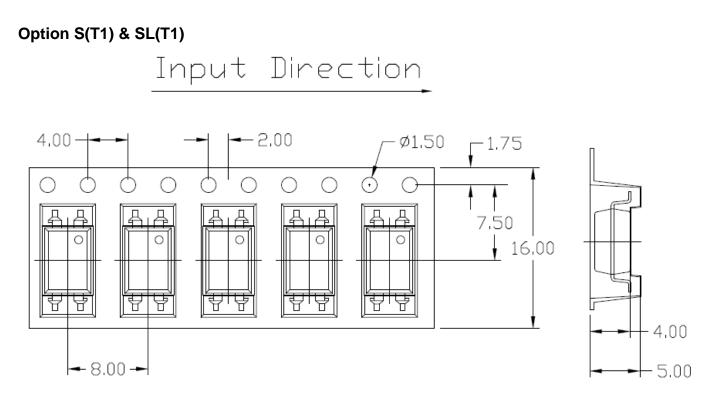
# CT521-1GB(V)(W)(Y)

- CT : Denotes "CT Micro"
- 521-1 : Part Number
- GB : CTR Rank
- V : VDE Safety Option( V or none)
- W : Lead form option (S, SL, SLM, M or none)
- Y : Tape and reel option (T1, T2 or none)

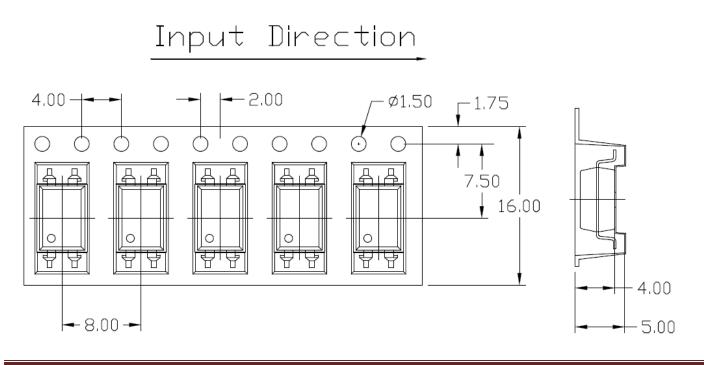
Option	Description	Quantity
None	Standard 4 Pin DIP	100 Units/Tube
М	Gullwing (400mil) Lead Forming	100 Units/Tube
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1500 Units/Reel
S(T2)	Surface Mount Lead Forming – With Option 2 Taping	1500 Units/Reel
SL(T1)	Surface Mount (Low Profile) Lead Forming- With Option 1 Taping	1500 Units/Reel
SL(T2)	Surface Mount (Low Profile) Lead Forming – With Option 2 Taping	1500 Units/Reel
SLM(T1)	Surface Mount (Gullwing) Lead Forming– With Option 1 Taping	1500 Units/Reel
SLM(T2)	Surface Mount (Gullwing) Lead Forming – With Option 2 Taping	1500 Units/Reel



## Carrier Tape Specifications Dimensions in mm unless otherwise stated

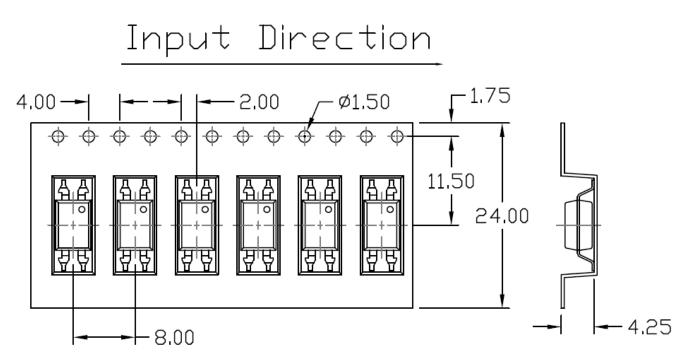


Option S(T2) & SL(T2)

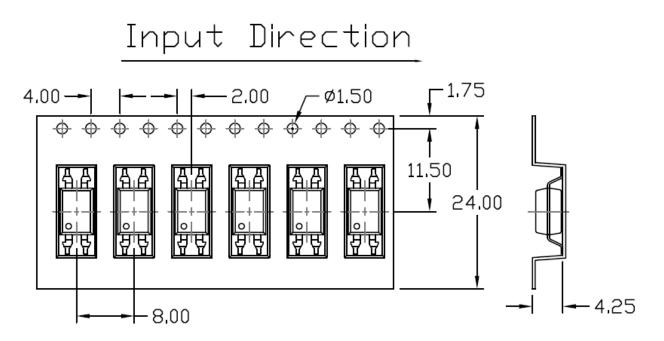




Option SLM(T1)



#### **Option SLM(T2)**





# Wave soldering (JEDEC22A111 compliant)

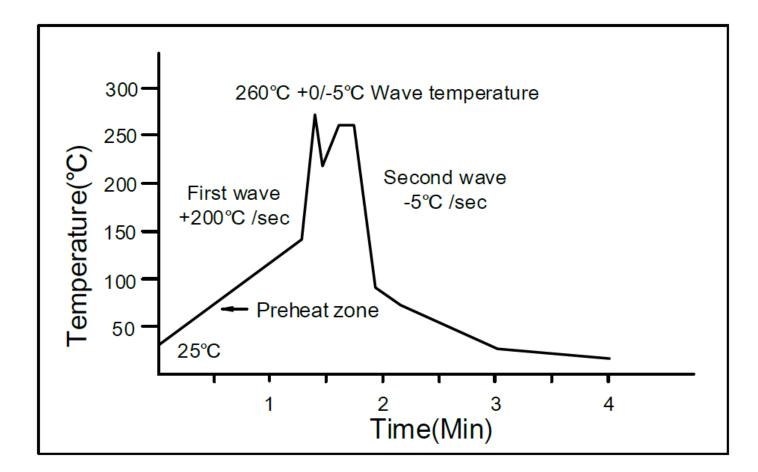
One time soldering is recommended within the condition of temperature.

Temperature: 260+0/-5°C.

Time: 10 sec.

Preheat temperature:25 to 140°C.

Preheat time: 30 to 80 sec.

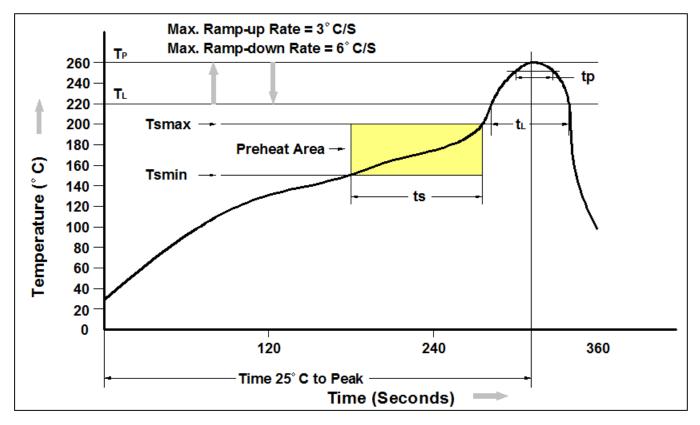


## Hand soldering by soldering iron

Allow single lead soldering in every single process. One time soldering is recommended. Temperature: 350+0/-5°C Time: 3 sec max.



## **Reflow Profile**



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t∟ to t⊳)	3°C/second max.
Liquidous Temperature (TL)	217°C
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t <sub>P</sub> ) within 5°C of 260°C	30 seconds
Ramp-down Rate $(T_P \text{ to } T_L)$	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



#### DISCLAIMER

CT MICRO RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. CT MICRO DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

DISCOLORATION MIGHT OCCUR ON THE PACKAGE SURFACE AFTER SOLDERING, REFLOW OR LONG TERM USE. THIS DOES NOT IMPACT THE PRODUCT PERFORMANCE NOR THE PRODUCT RELIABILITY.

CT MICRO ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT EXPRESS WRITTEN APPROVAL OF CT MICRO INTERNATIONAL CORPORATION.

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instruction for use provided in the labelling, can be reasonably expected to result in significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for High Speed Optocouplers category:

Click to view products by CT Micro International manufacturer:

Other Similar products are found below :

6N136F HCPL-2201-300 JAN4N24 610737H HCPL2630M HCPL2630SM PS9817A-1-F3-AX PS9821-2-F3-AX TLP2766A(E TLP2766A(LF4,E PS9121-F3-AX TLP5774H(TP4,E TLP5771H(TP,E TLP2304(E(O 054279X HCPL2631SD HCPL-2730-500E TLP118(TPL,E) TLP2309(E(T TLP2366(TPL,E TLP521-2XGB TLP621-2XGB JANTXV4N24U 8102802PC 5962-8767902XA 5962-8876801XA 5962-8957101PA SFH6318T 6N135-300E TIL198 TLP104(TPR,E) TLP2309(TPL,E) TLP2355(TPL,E TLP2358(E) TLP521-4GR TLP521-4XGB TLP621XSM 5962-8876801PA IS281-4GB IS2805-4 IS181GR ICPL2630 ICPL2531 ICPL2601 ICPL2530 5962-8876801PC TLP2301 TLP2301(E(T TLP2362(TPR,E FOD0710R2